

## **Description**

The VSM15P05 uses advanced trench technology and design to provide excellent  $R_{\text{DS}(\text{ON})}$  with low gate charge. It can be used in a wide variety of applications.

#### **General Features**

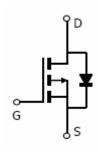
- V<sub>DS</sub> =-55V,I<sub>D</sub> =-15A  $R_{DS(ON)}$  <75m $\Omega$  @  $V_{GS}$ =-10V
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Excellent package for good heat dissipation

### **Application**

- Power switching application
- Hard switched and high frequency circuits
- DC-DC Converter



TO-252



Schematic Diagram

### **Package Marking and Ordering Information**

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
VSM15P05-T2	VSM15P05	TO-252	-	-	-

## Absolute Maximum Ratings (T<sub>c</sub>=25 ℃ unless otherwise noted)

Parameter	Symbol	Limit	Unit	
Drain-Source Voltage	V <sub>DS</sub>	-55	V	
Gate-Source Voltage	V <sub>G</sub> s	±20	V	
Drain Current-Continuous	I <sub>D</sub>	-15	A A	
Drain Current-Continuous(T <sub>C</sub> =100 °C)	I <sub>D</sub> (100℃)	-10		
Pulsed Drain Current	I <sub>DM</sub>	-50	А	
Maximum Power Dissipation	P <sub>D</sub>	35	W	
Operating Junction and Storage Temperature Range	$T_{J}, T_{STG}$	-55 To 175	°C	

#### **Thermal Characteristic**

Thermal Resistance ,Junction-to-Case <sup>(Note 2)</sup>	R <sub>θJC</sub>	4.3	°C/W
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# Electrical Characteristics (T<sub>C</sub>=25 <sup>°</sup>C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =-250μA	-55	-	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =-55V,V <sub>GS</sub> =0V	-	-	1	μA
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage			-1.5	-2.6	-3.5	V
Drain-Source On-State Resistance			-	60	75	mΩ
Forward Transconductance	<b>g</b> FS	V <sub>DS</sub> =-15V,I <sub>D</sub> =-5A	16	-	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	C <sub>lss</sub>	.,	-	1450	-	PF
Output Capacitance	Coss	$V_{DS}$ =-20V, $V_{GS}$ =0V, F=1.0MHz	-	145	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>	F=1.UIVIHZ	-	110	-	PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	t <sub>d(on)</sub>	$V_{DD}$ =-30V, $R_L$ =30 $\Omega$ $V_{GS}$ =-10V, $R_{GEN}$ =6 $\Omega$	-	8	-	nS
Turn-on Rise Time	t <sub>r</sub>		-	9	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>		-	65	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	30	-	nS
Total Gate Charge	Qg	.,	-	26	-	nC
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS}$ =-30V, $I_{D}$ =-5A,	-	4.5	-	nC
Gate-Drain Charge	$Q_{gd}$	V <sub>GS</sub> =-10V	-	7	-	nC
Drain-Source Diode Characteristics	<u> </u>		•			
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =-15A	-	-	1.2	V
Diode Forward Current (Note 2)	Is		-	-	-15	Α

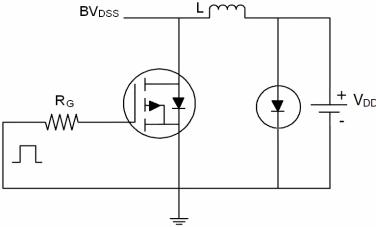
#### Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- 3. Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.
- **4.** Guaranteed by design, not subject to production

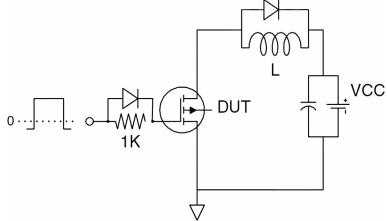


## **Test Circuit**

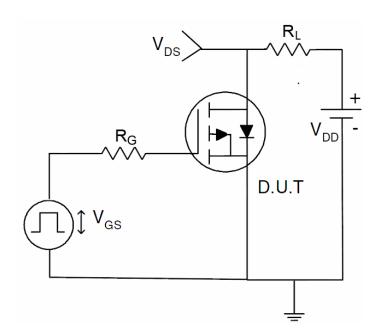
## 1) E<sub>AS</sub> Test Circuit



## 2) Gate Charge Test Circuit

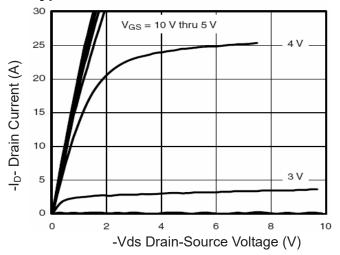


## 3) Switch Time Test Circuit

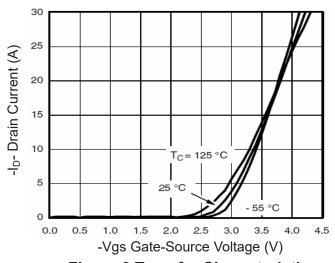




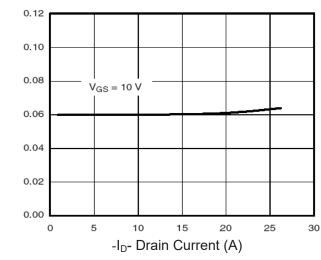
### Typical Electrical and Thermal Characteristics (Curves)



**Figure 1 Output Characteristics** 

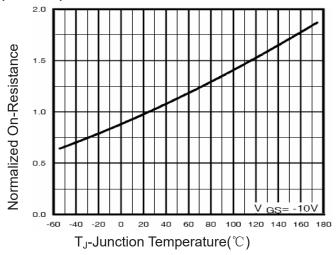


**Figure 2 Transfer Characteristics** 



Rdson On-Resistance( (2)

Figure 3 Rdson- Drain Current



**Figure 4 Rdson-Junction Temperature** 

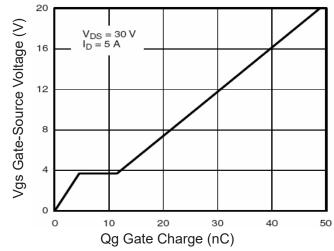


Figure 5 Gate Charge

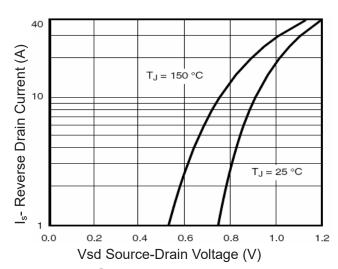


Figure 6 Source- Drain Diode Forward



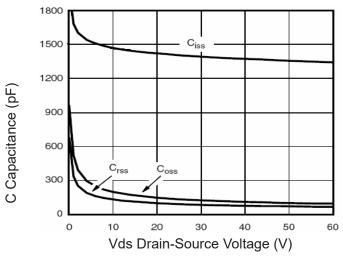
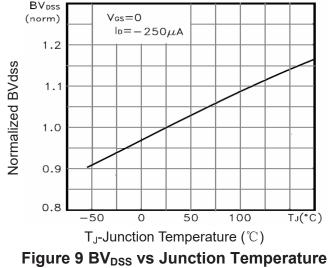


Figure 7 Capacitance vs Vds



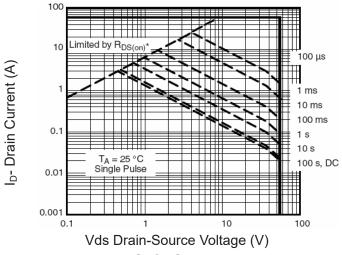


Figure 8 Safe Operation Area

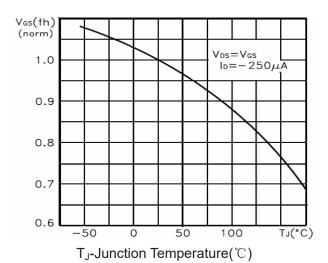


Figure 10 V<sub>GS(th)</sub> vs Junction Temperature

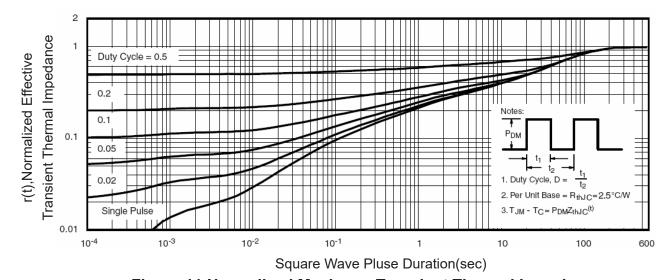


Figure 11 Normalized Maximum Transient Thermal Impedance